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P-Channel 100-V (D-S) Super Junction MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	R _{DS(on)} (mΩ)(Typ.)	I _D (A) ^a	Q _g (Typ.)			
- 100	36 at V _{GS} = - 10 V	25	46 nC			
- 100	45 at V _{GS} = - 4.5 V	- 35	46 NC			

FEATURES

- DT-SJ Power MOSFET
- 100 % R g and UIS Tested
- Very low on-resistance R_{DS(on)}

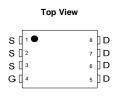
Pb-free

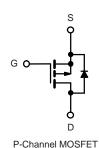
ROHS COMPLIAN

APPLICATIONS

- PWM Applications
- Load Switch
- Power Management







ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	LIMIT	UNIT			
Drain-Source Voltage	V_{DS}	- 100	V			
Gate-Source Voltage	V_{GS}	± 20	V			
Continuous Dunin Comment	T _C = 25 °C		- 35			
Continuous Drain Current	T _C = 100 °C	I _D	- 21			
Continuous Source Current (Diode Conduc	I _S	- 35	Α			
Pulsed Drain Current ^a		I _{DM}	- 140			
Single Pulse Avalanche Energy	L = 0.5 mH	E _{AS}	330	mJ		
Maximum Dawar Dissinationh	T _C = 25 °C	D	95	W		
Maximum Power Dissipation ^b	T _C = 100 °C	P_D	48	VV		
Operating Junction and Storage Temperatu	T _J , T _{stq}	- 55 to + 150	°C			

THERMAL RESISTANCE RATINGS						
PARAMETER	SYMBOL	LIMIT	UNIT			
Junction-to-Case (Drain) ^{C,d}	RthJC	1.32	°C/W			

Notes:

- a. $T_C = 25$ °C.
- b. Surface mounted on 1" x 1" FR4 board.
- c. t = 10 s
- d. Maximum under steady state conditions is 2.5 °C/W.



Parameter	Symbol	Test Conditions	Min .	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_{D} = -250 \mu\text{A}$	- 100			V	
Gate-Source Threshold Voltage		$V_{DS} = V_{GS}, I_D = -250 \mu A$	- 1		- 3	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zara Oata Wallana Basin Oamani	,	V _{DS} = -100 V, V _{GS} = 0 V			1		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = -80 V, V _{GS} = 0 V, T _J = 55 °C			10	μA	
Davis Oceans Oc. Otata Davista and	P	V _{GS} = - 10 V, I _D = - 20 A		36	42	mΩ	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 20 A		45	44		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = -5 \text{ V}, I_{D} = -20 \text{ A}$		20		S	
Dynamic ^b					<u> </u>		
Input Capacitance	C _{iss}			1370		pF	
Output Capacitance	C _{oss}	$V_{DS} = -50 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		190			
Reverse Transfer Capacitance	C _{rss}]		11			
Total Gate Charge	Qg			46		nC	
Gate-Source Charge	Q _{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -50 \text{ V}, I_{D} = -20 \text{ A}$		10			
Gate-Drain Charge	Q_{gd}]		6			
Gate Resistance	R _g	f = 1 MHz		52		Ω	
Turn-On Delay Time	t _{d(on)}			14			
Rise Time	t _r	$V_{DS} = -30 \text{ V}, I_{D} = -20 \text{ A},$		9		ns	
Turn-Off Delay Time	t _{d(off)}	$VGS = -10 \text{ V}, Rg = 2 \Omega$		41			
Fall Time	t _f	1		11			
Drain-Source Body Diode Characteristics	;			•			
Continuous Source-Drain Diode Current	I _S	T _A = 25 °C			- 35	Α	
Pulse Diode Forward Current ^a	I _{SM}				- 140	А	
Body Diode Voltage	V_{SD}	I _S = - 20 A			- 1.2	V	
Body Diode Reverse Recovery Time	ody Diode Reverse Recovery Time			47		ns	
Body Diode Reverse Recovery Charge	Q _{rr}	I_F = - 20 A, di/dt = 100 A/ μ s, T_J = 25 °C		88		nC	

Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

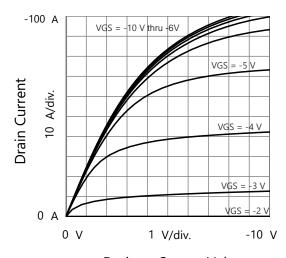
a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

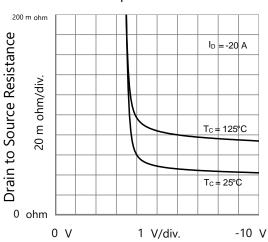




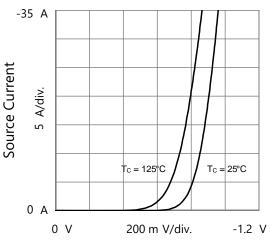
TYPICAL CHARACTERISTICS (25 C, unless otherwise noted)



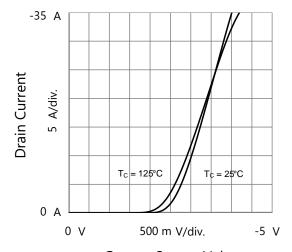
Drain to Source Voltage Output Characteristics



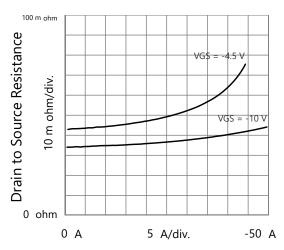
Gate to Source Voltage
Drain to Source Resistance vs. Gate to Source Voltage



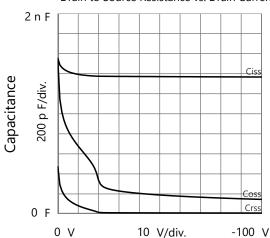
Source to Drain Voltage Body Diode Forward Characteristics



Gate to Source Voltage Transfer Characteristics



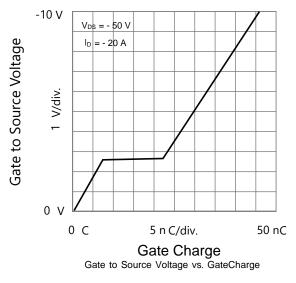
Drain Current
Drain to Source Resistance vs. Drain Current

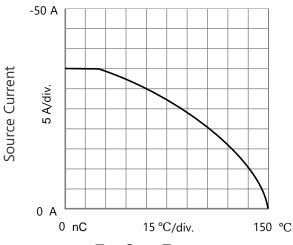


Drain to Source Voltage Capacitances

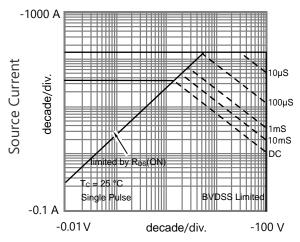


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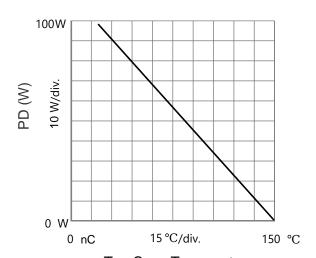






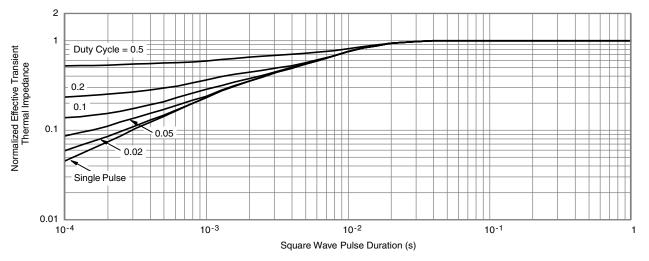


Source to Drain Voltage Safe Operating Area, Junction-to-Ambient



T_C - Case Temperature

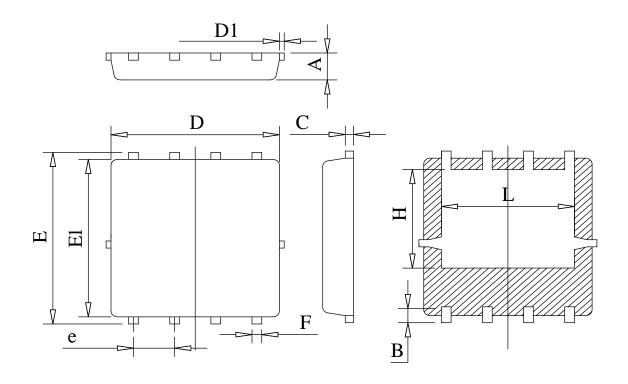
Power Derating



Normalized Thermal Transient Impedance, Junction-to-Case



DFN5X6-8L PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

Unit: mm

Symbol	Min	Тур	Max
A	0.78	0.95	1.12
В	0.45	0.58	0.78
С	0.18	0.254	0.36
D	4.70	5.20	5.45
D1			0.18
Е	5.85	6.05	6.25
E1	5.38	5.55	5.98
e	1.15	1.27	1.40
F	0.18	0.30	0.52
Н	3.25	3.47	3.70
L	3.75	4.00	4.25





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